

### January 2005

# **1N4153** Small Signal Diode



DO-35 Color Band Denotes Cathode

# Absolute Maximum Ratings \* T<sub>a</sub> = 25°C unless otherwise noted

| Symbol             | Parameter   | Value       | Unit   |
|--------------------|---|-------------|--------|
| V <sub>RRM</sub>   | Maximum Repetitive Reverse Voltage 75   |             | V      |
| I <sub>F(AV)</sub> | Average Rectified Forward Current 200   |             | mA     |
| I <sub>FSM</sub>   | Non-repetitive Peak Forward Surge Current1.0Pulse Width = 1.0 second1.0Pulse Width = 1.0 microsecond4.0 |             | A<br>A |
| T <sub>STG</sub>   | Storage Temperature Range   | -65 to +200 | °C     |
| TJ                 | Operating Junction Temperature  | 175         | °C     |

\* These ratings are limiting values above which the serviceability of the diode may be impaired.

#### NOTES:

1) These ratings are based on a maximum junction temperature of 200 degrees C.

2) These are steady limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

# **Thermal Characteristics**

| Symbol                | Parameter                               | Value | Unit |  |
|-----------------------|---|-------|------|--|
| P <sub>D</sub>        | Power Dissipation                       | 500   | mW   |  |
| $R_{	extsf{	heta}JA}$ | Thermal Resistance, Junction to Ambient | 300   | °C/W |  |

# Electrical Characteristics T<sub>C</sub> = 25°C unless otherwise noted

| Symbol           | Parameter             | Conditions  | Min.   | Max  | Units                 |
|------------------|-----------------------|---|--|--|-----------------------|
| V <sub>R</sub>   | Breakdown Voltage     | I <sub>R</sub> = 5μA  | 75   |  | V                     |
| V <sub>F</sub>   | Forward Voltage       | $I_F = 0.1mA$<br>$I_F = 0.25mA$<br>$I_F = 1.0mA$<br>$I_F = 2.0mA$<br>$I_F = 10mA$<br>$I_F = 20mA$ | 0.49<br>0.53<br>0.59<br>0.62<br>0.70<br>0.74 | 0.55<br>0.59<br>0.67<br>0.70<br>0.81<br>0.88 | V<br>V<br>V<br>V<br>V |
| I <sub>R</sub>   | Reverse Leakage       | V <sub>R</sub> = 50V<br>V <sub>R</sub> = 50V, T <sub>A</sub> = 150°C                              |  | 50<br>50                                     | nA<br>μA              |
| C <sub>T</sub>   | Total Capacitance     | V <sub>R</sub> = 0, f = 1.0MHz  |  | 2  | pF                    |
| t <sub>rr1</sub> | Reverse Recovery Time | I <sub>F</sub> = I <sub>R</sub> = 10mA, R <sub>L</sub> = 100Ω, I <sub>rr</sub> = 1.0mA            |  | 4  | ns                    |
| t <sub>rr2</sub> |                       | $I_F = 10mA, V_R = 6.0V$<br>$R_L = 100\Omega, I_{rr} = 1.0mA$                                     |  | 2  | ns                    |

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Rev. 115